

/ Descriptions

WR0553 ММ QSQ æ Ñ ç s ll 1 Silicon NPN transistor in a TO-220 Plastic Package.

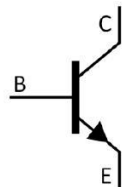
/ Features

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High h_{FE} , low saturation voltage, complementary pair with KTB988.

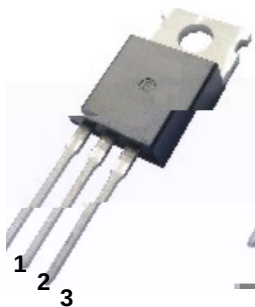
/ Applications

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General purpose application.

/ Equivalent Circuit



/ Pinning



PIN1 ⌘ Base PIN 2 ⌘ Collector PIN 3 ⌘ Emitter

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	O	Y	GR
h_{FE} Range	60 120	100 200	150 300

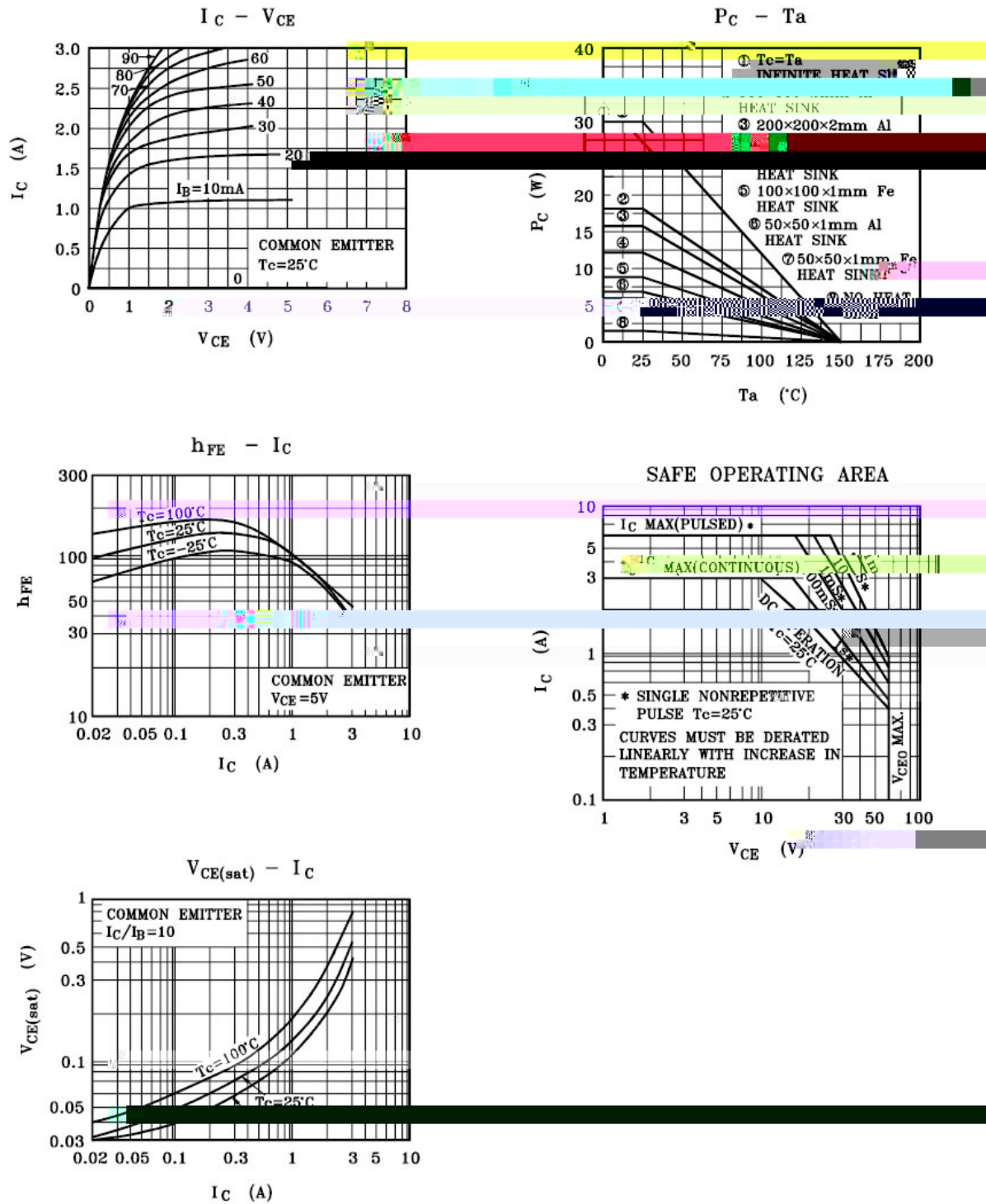
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	60	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	3.0	A
Base Current	I_B	500	mA
Collector Power Dissipation	P_C	2.0	W
Collector Power Dissipation	$P_C(T_c=25)$	30	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

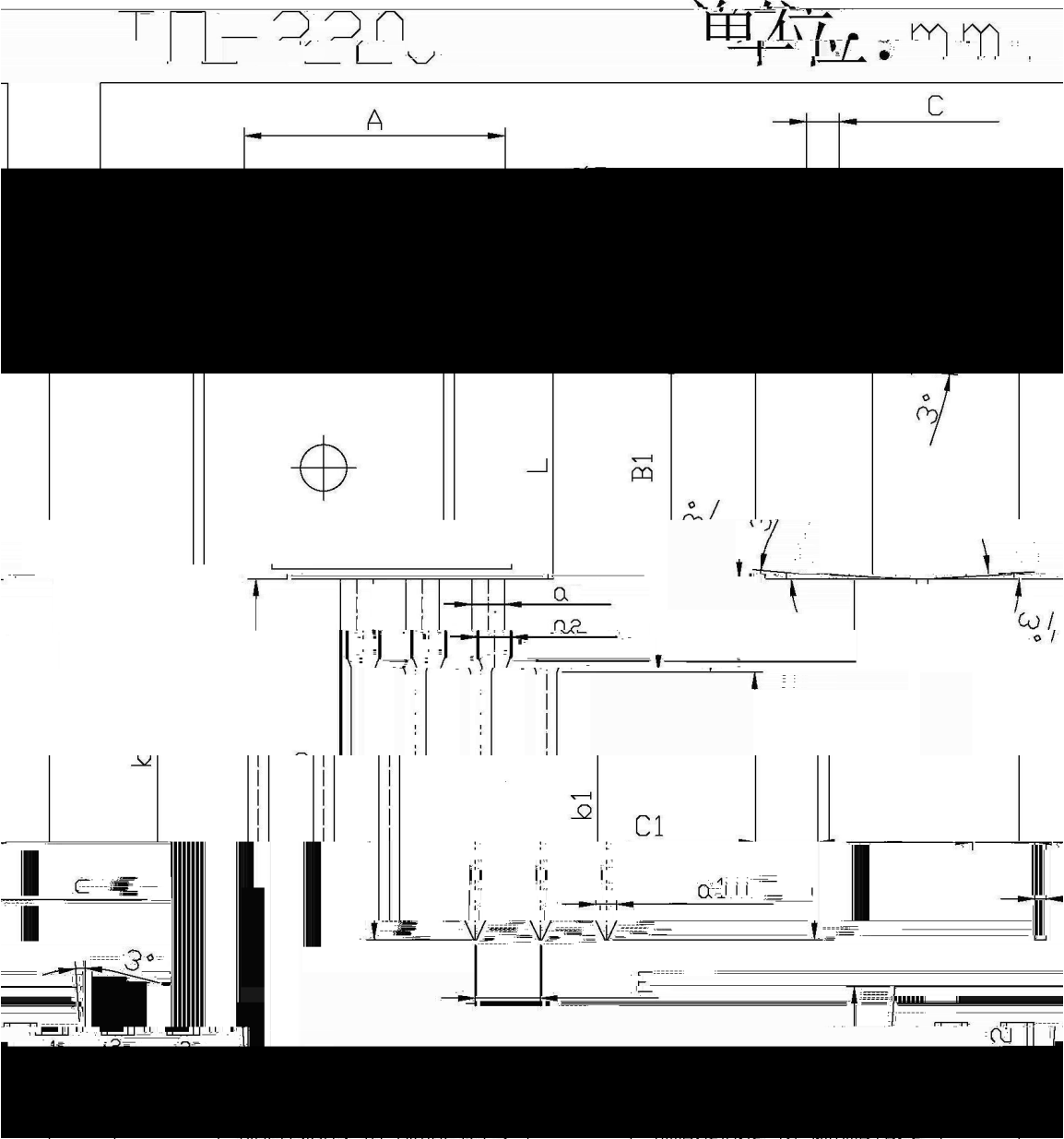
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=50mA$ $I_B=0$	60			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=60V$ $I_E=0$			100	A
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=7.0V$ $I_C=0$			100	A
DC Current Gain	h_{FE}	$V_{CE}=5.0V$ $I_C=0.5A$	60		300	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=2.0A$ $I_B=0.2A$		0.25	1.0	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=5.0A$ $I_C=0.5A$		0.7	1.0	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $I_C=0.5A$		3.0		MHz
Collector output capacitance	C_{ob}	$V_{CB}=10V$ $I_E=0$ $f=1.0MHz$		35		pF
Turn-On Time	t_{on}	$-I_{B1}=I_{B2}=0.2A$ $V_{CC}=-30V$		0.65		s
Storage Time	t_{stg}			1.3		
Fall Time	t_f			0.65		

/ Electrical Characteristic Curve

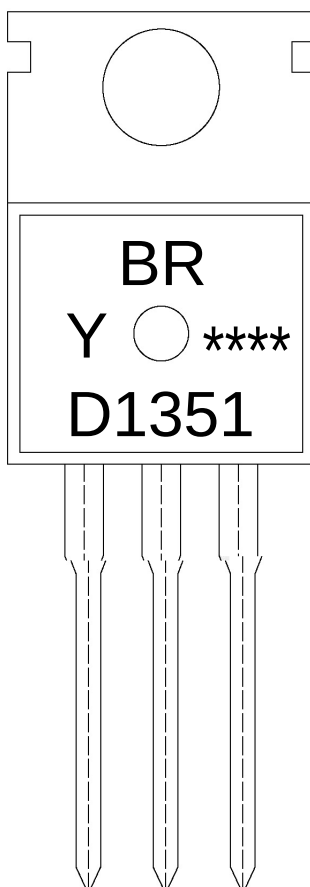


/ Package Dimensions



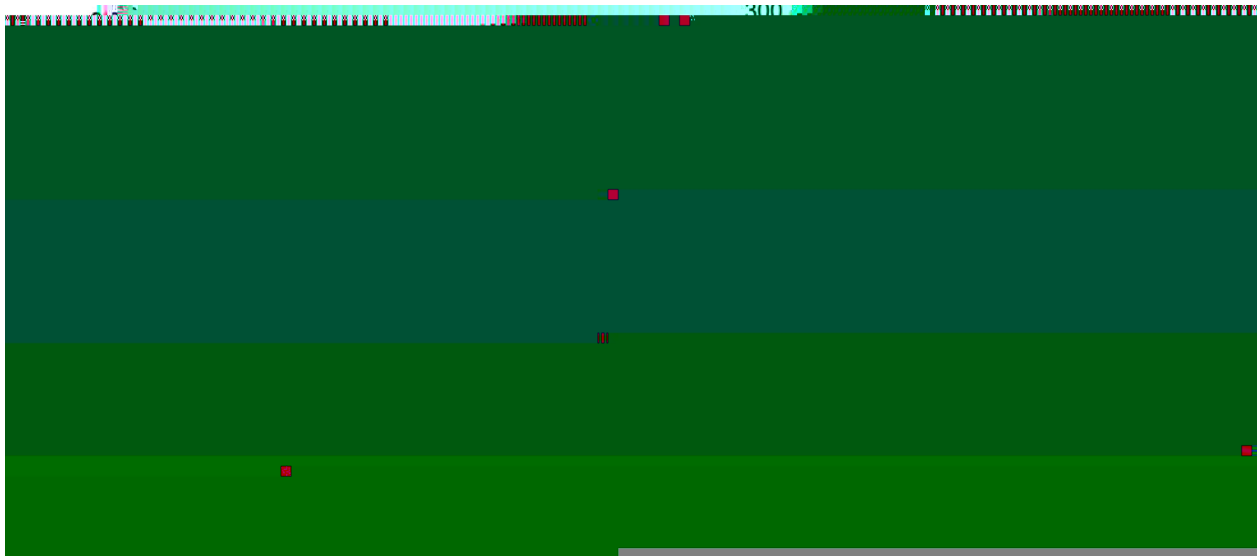
Dimensions in Millimeters			Dimensions in Millimeters		
Symbol	Min	Max	Symbol	Min	Max
A	1.4	9.8	C	10.2	11.2
B1	9.4	15.7	B2	16.1	17.0

/ Marking Instructions



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EU X	ꯏ ꯑ ꯍ ꯓ
G4684 X	ꯏ ꯑ ꯍ ꯓ
\=	ꯏ k _{IH} ꯍ ꯓ
---- X	ꯏ ꯑ ꯍ ꯓ ꯍ ꯑ ꯍ ꯓ ꯍ ꯑ ꯍ ꯓ
Note:	
BR:	Company Code
D1351:	Product Type.
Y:	h _{FE} Classifications Symbol
****:	Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



1. 预加热: 25~150s, 时间: 60~90sec;
2. 峰值温度: 255±5℃, 持续时间: 5±0.5sec;
3. 冷却速度: 2~10℃/sec.

- Note:
1. Preheating: 25~150s, Time: 60~90sec.
2. Peak Temp.: 255±5℃, Duration: 5±0.5sec.
3. Cooling Speed: 2~10℃/sec.

/ Resistance to Soldering Heat Test Conditions

预加热: 270±5℃, 时间: 10±1 sec. Temp.: 270±5 Time: 10±1 sec

/ Packaging SPEC.

散装 / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

管装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-220/F	50	20	1,000	5	5,000	532×31.4×5.5	555×164×50	575×290×180

/ Notices